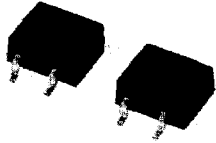


FS3VS-14A

HIGH-SPEED SWITCHING USE

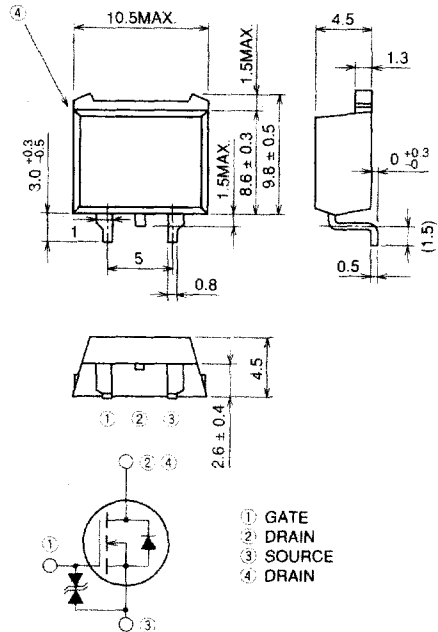
FS3VS-14A



- V_{DS} 700V
- $r_{DS(ON)}$ (MAX) 4.75Ω
- I_D 3A

OUTLINE DRAWING

Dimensions in mm



TO-220S

APPLICATION

SMPS, DC-DC Converter, battery charger, power supply of printer, copier, HDD, FDD, TV, VCR, personal computer etc.

MAXIMUM RATINGS (Tc = 25°C)

Symbol	Parameter	Conditions	Ratings	Unit
V_{DS}	Drain-source voltage	$V_{GS} = 0V$	700	V
V_{GS}	Gate-source voltage	$V_{DS} = 0V$	± 30	V
I_D	Drain current		3	A
I_{DM}	Drain current (Pulsed)		9	A
P_D	Maximum power dissipation		85	W
T_{ch}	Channel temperature		-55 ~ +150	°C
T_{stg}	Storage temperature		-55 ~ +150	°C
—	Weight	Typical value	1.2	g

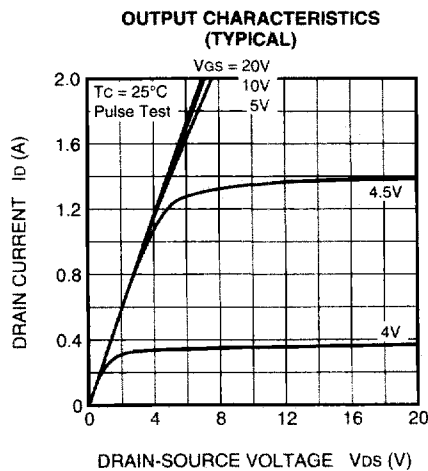
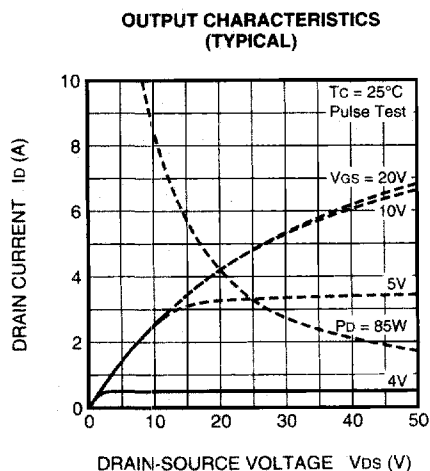
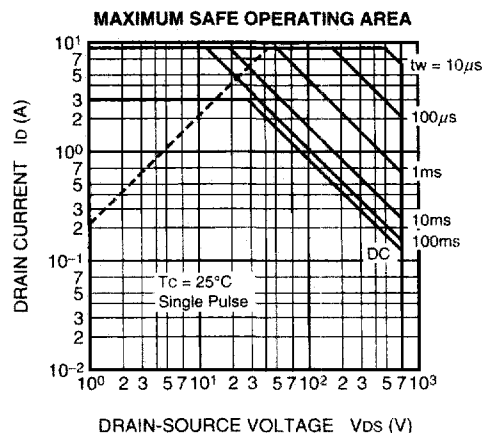
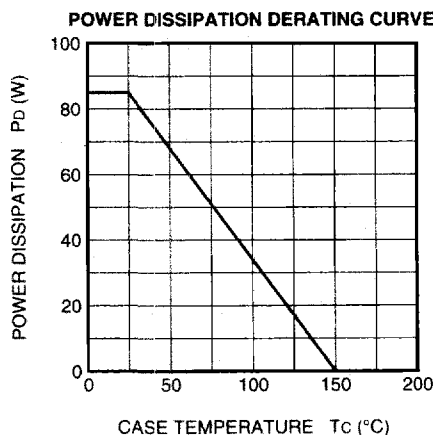
FS3VS-14A

HIGH-SPEED SWITCHING USE

ELECTRICAL CHARACTERISTICS ($T_{ch} = 25^{\circ}\text{C}$)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
$V_{(BR)DSS}$	Drain-source breakdown voltage	$I_D = 1\text{mA}$, $V_{GS} = 0\text{V}$	700	—	—	V
$V_{(BR)GSS}$	Gate-source breakdown voltage	$I_{GS} = \pm 100\mu\text{A}$, $V_{DS} = 0\text{V}$	± 30	—	—	V
I_{GSS}	Gate leakage current	$V_{GS} = \pm 25\text{V}$, $V_{DS} = 0\text{V}$	—	—	± 10	μA
I_{DSS}	Drain current	$V_{DS} = 700\text{V}$, $V_{GS} = 0\text{V}$	—	—	1	mA
$V_{GS(th)}$	Gate-source threshold voltage	$I_D = 1\text{mA}$, $V_{DS} = 10\text{V}$	2	3	4	V
$r_{DS(ON)}$	Drain-source on-state resistance	$I_D = 1.5\text{A}$, $V_{GS} = 10\text{V}$	—	3.65	4.75	Ω
$V_{DS(ON)}$	Drain-source on-state voltage	$I_D = 1.5\text{A}$, $V_{GS} = 10\text{V}$	—	5.48	7.13	V
y_{fs}	Forward transfer admittance	$I_D = 1.5\text{A}$, $V_{DS} = 10\text{V}$	1.4	2.4	—	S
C_{iss}	Input capacitance	$V_{DS} = 25\text{V}$, $V_{GS} = 0\text{V}$, $f = 1\text{MHz}$	—	460	—	pF
C_{oss}	Output capacitance		—	50	—	pF
C_{rss}	Reverse transfer capacitance		—	9	—	pF
$t_d(ON)$	Turn-on delay time	$V_{DD} = 200\text{V}$, $I_D = 1.5\text{A}$, $V_{GS} = 10\text{V}$, $R_{GEN} = R_{GS} = 50\Omega$	—	12	—	ns
t_r	Rise time		—	15	—	ns
$t_d(OFF)$	Turn-off delay time		—	52	—	ns
t_f	Fall time		—	22	—	ns
V_{SD}	Source-drain voltage	$I_S = 1.5\text{A}$, $V_{GS} = 0\text{V}$	—	1.0	1.5	V
$R_{th(ch-c)}$	Thermal resistance	Channel to case	—	—	1.47	$^{\circ}\text{C/W}$

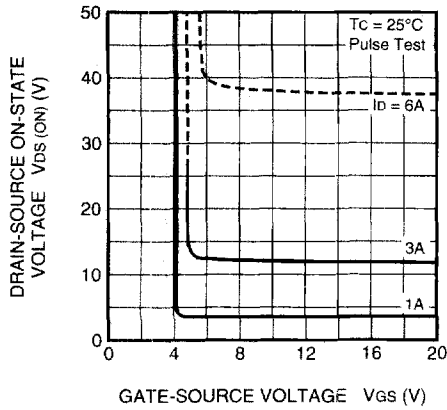
PERFORMANCE CURVES



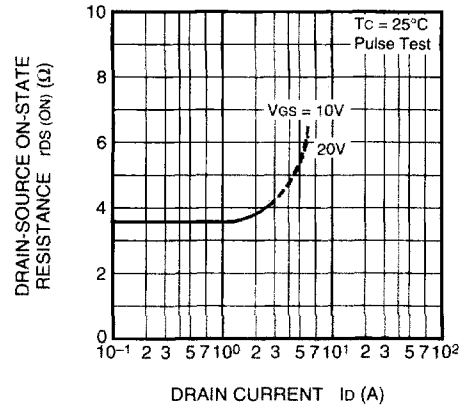
FS3VS-14A

HIGH-SPEED SWITCHING USE

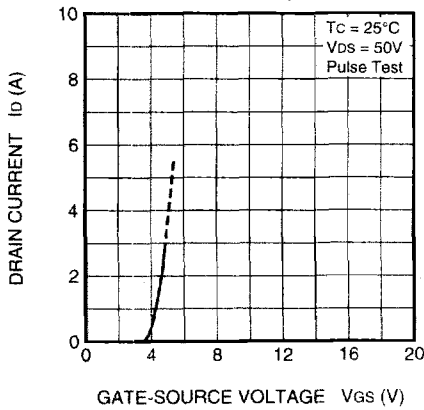
ON-STATE VOLTAGE VS.
GATE-SOURCE VOLTAGE
(TYPICAL)



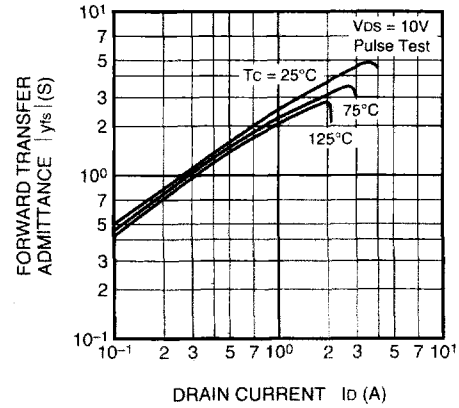
ON-STATE RESISTANCE VS.
DRAIN CURRENT
(TYPICAL)



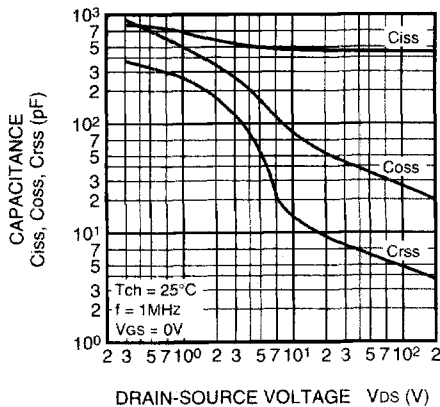
TRANSFER CHARACTERISTICS
(TYPICAL)



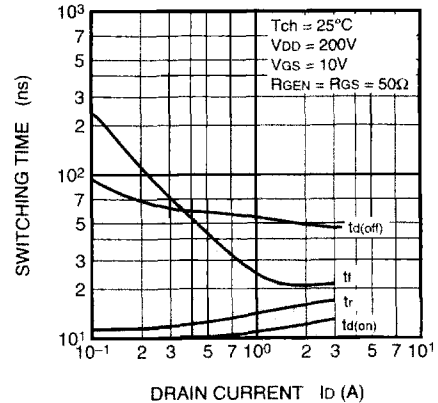
FORWARD TRANSFER ADMITTANCE
VS. DRAIN CURRENT
(TYPICAL)



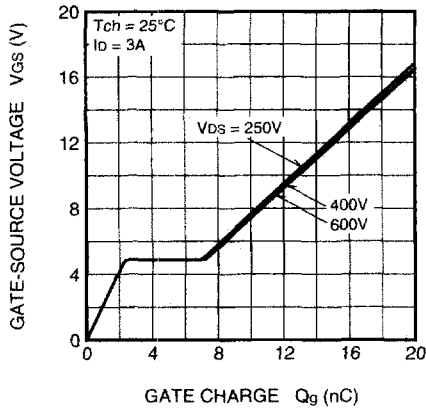
CAPACITANCE VS.
DRAIN-SOURCE VOLTAGE
(TYPICAL)



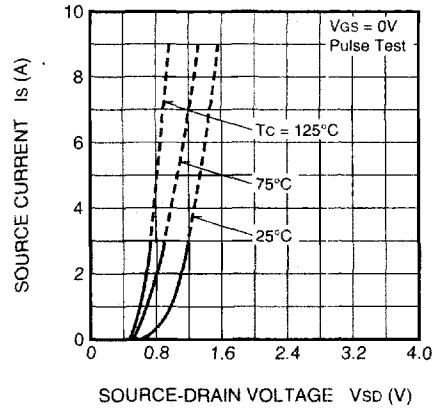
SWITCHING CHARACTERISTICS
(TYPICAL)



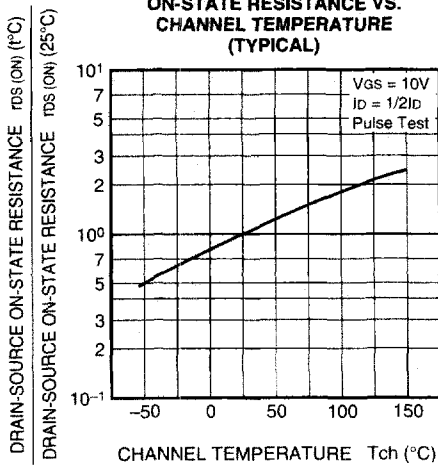
GATE-SOURCE VOLTAGE
VS. GATE CHARGE
(TYPICAL)



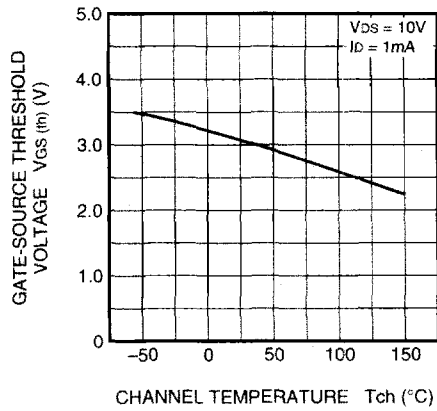
SOURCE-DRAIN DIODE
FORWARD CHARACTERISTICS
(TYPICAL)



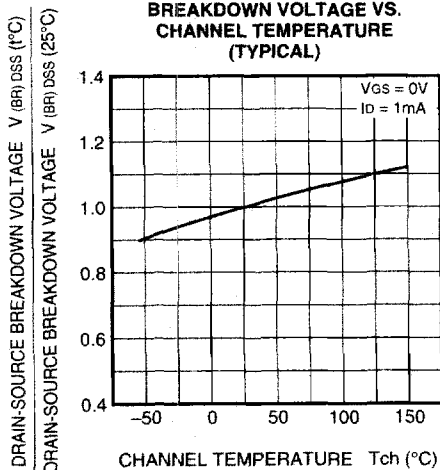
ON-STATE RESISTANCE VS.
CHANNEL TEMPERATURE
(TYPICAL)



THRESHOLD VOLTAGE VS.
CHANNEL TEMPERATURE
(TYPICAL)



BREAKDOWN VOLTAGE VS.
CHANNEL TEMPERATURE
(TYPICAL)



TRANSIENT THERMAL IMPEDANCE
CHARACTERISTICS

